

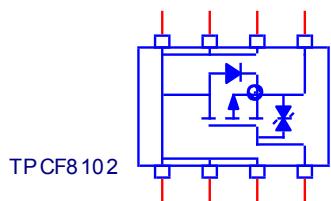
Device Modeling Report

COMPONENTS: Power MOSFET (Model Parameter)
PART NUMBER: TPCF8102
MANUFACTURER: TOSHIBA
Body Diode (Model Parameter) / ESD Protection Diode



Bee Technologies Inc.

Circuit Configuration

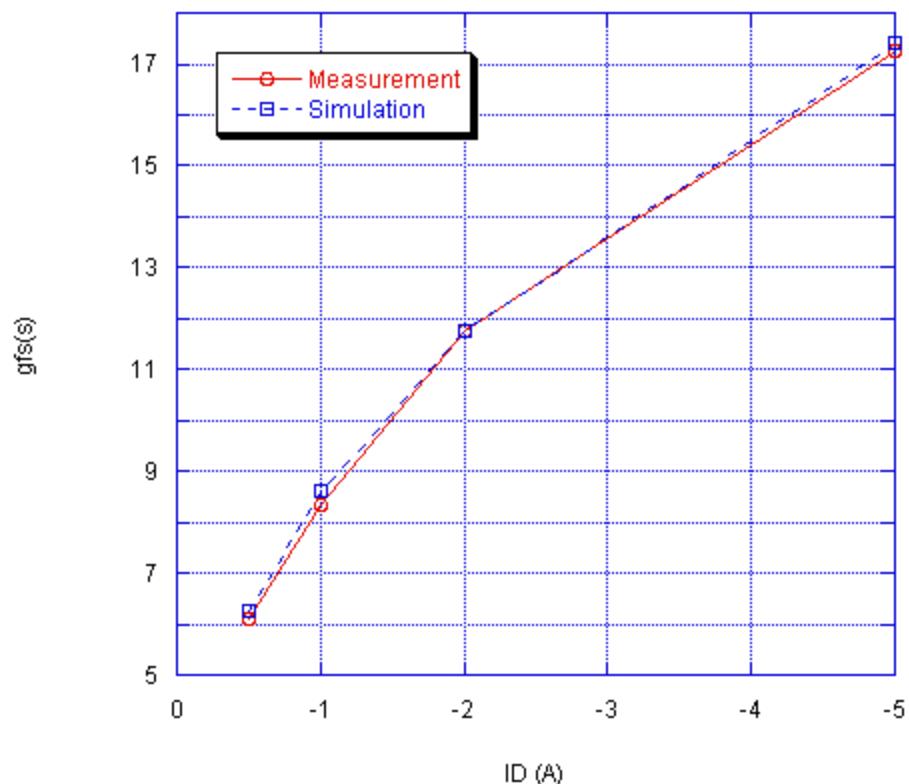


MOSFET MODEL

Pspice model Parameter	Model description
LEVEL	
L	Channel Length
W	Channel Width
KP	Transconductance
RS	Source Ohmic Resistance
RD	Ohmic Drain Resistance
VTO	Zero-bias Threshold Voltage
RDS	Drain-Source Shunt Resistance
TOX	Gate Oxide Thickness
CGSO	Zero-bias Gate-Source Capacitance
CGDO	Zero-bias Gate-Drain Capacitance
CBD	Zero-bias Bulk-Drain Junction Capacitance
MJ	Bulk Junction Grading Coefficient
PB	Bulk Junction Potential
FC	Bulk Junction Forward-bias Capacitance Coefficient
RG	Gate Ohmic Resistance
IS	Bulk Junction Saturation Current
N	Bulk Junction Emission Coefficient
RB	Bulk Series Resistance
PHI	Surface Inversion Potential
GAMMA	Body-effect Parameter
DELTA	Width effect on Threshold Voltage
ETA	Static Feedback on Threshold Voltage
THETA	Modility Modulation
KAPPA	Saturation Field Factor
VMAX	Maximum Drift Velocity of Carriers
XJ	Metallurgical Junction Depth
UO	Surface Mobility

Transconductance Characteristic

Circuit Simulation Result

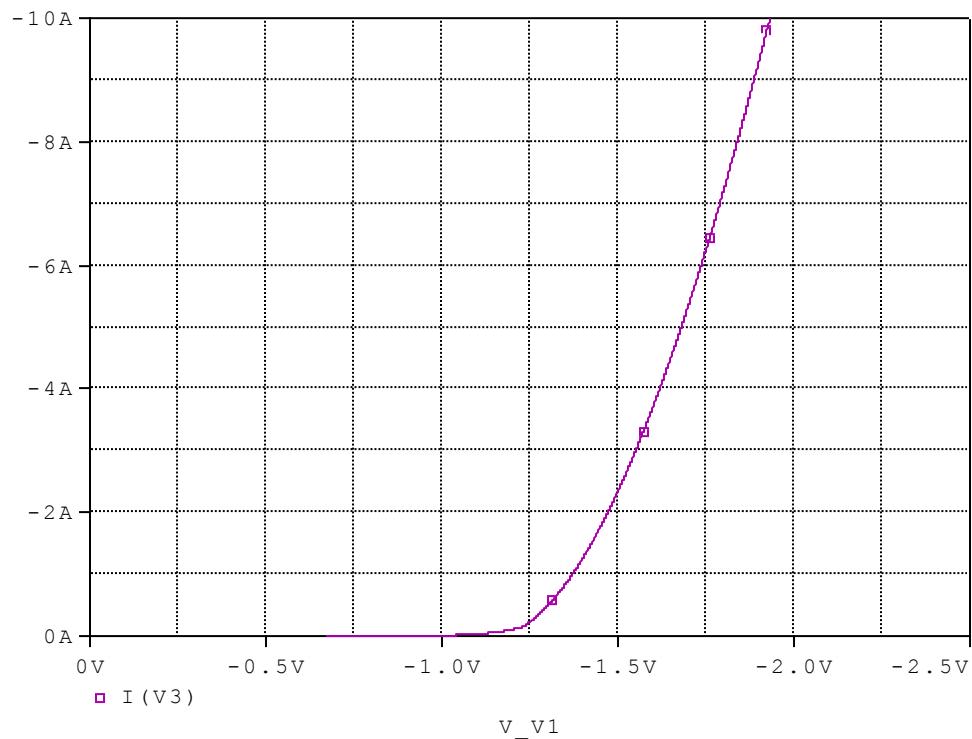


Comparison table

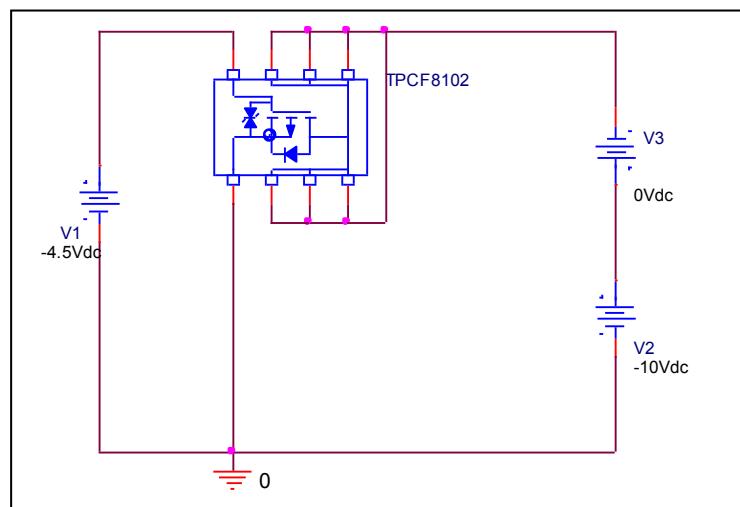
Id(A)	gfs		Error(%)
	Measurement	Simulation	
-0.500	6.097	6.250	2.509
-1.000	8.333	8.621	3.452
-2.000	11.765	11.765	-0.002
-5.000	17.240	17.422	1.053

V_{gs}-I_d Characteristic

Circuit Simulation result

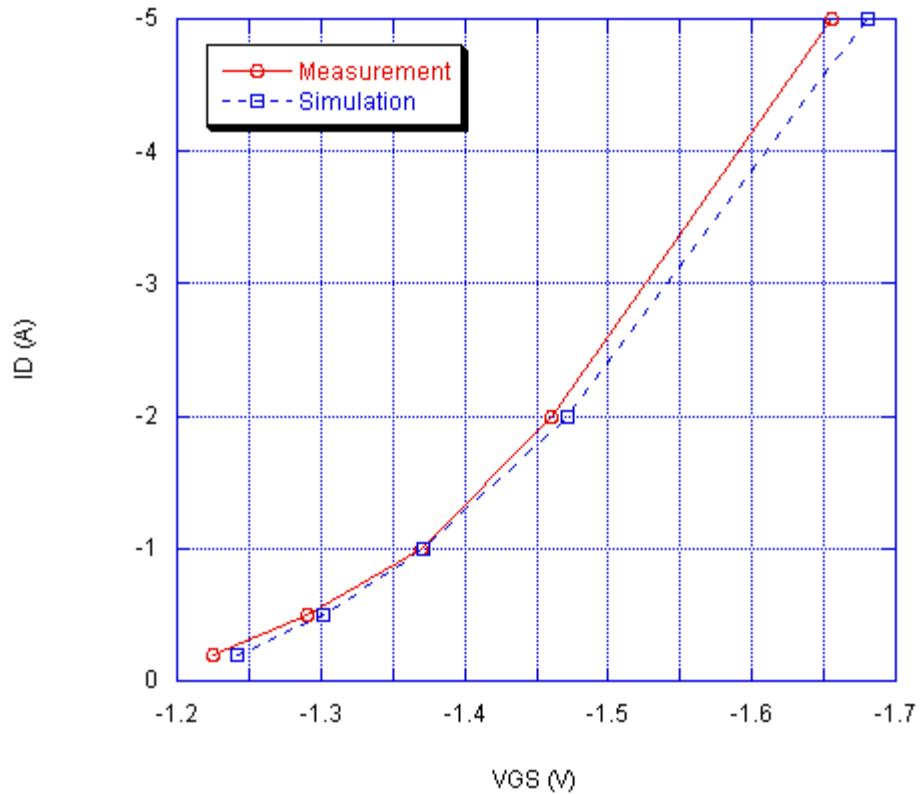


Evaluation circuit



Comparison Graph

Circuit Simulation Result

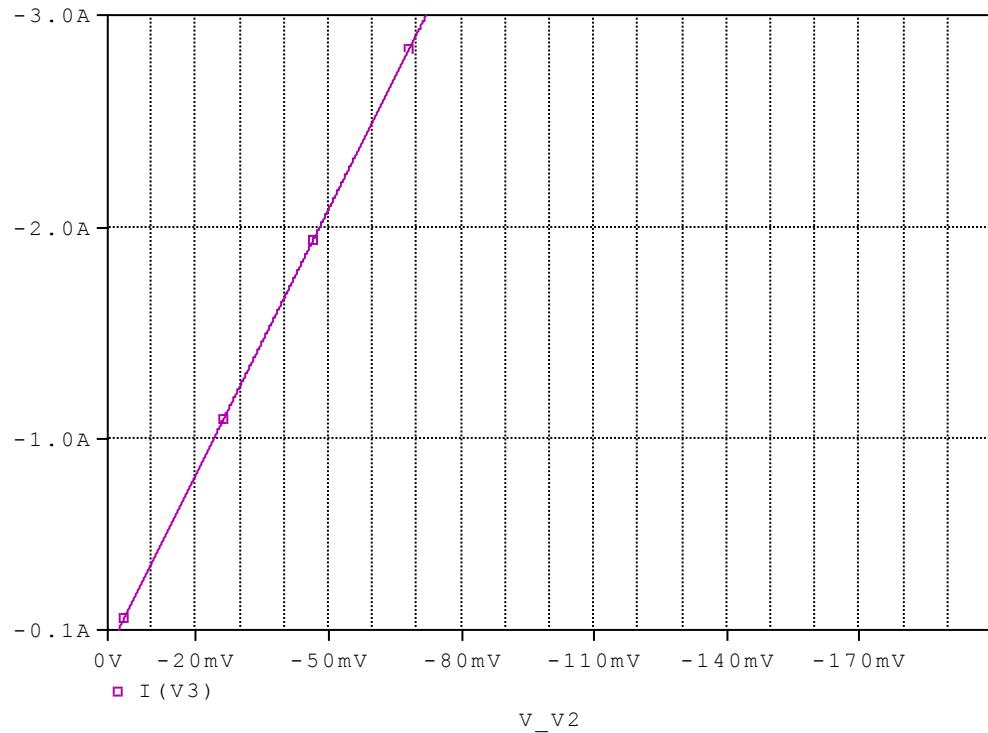


Simulation Result

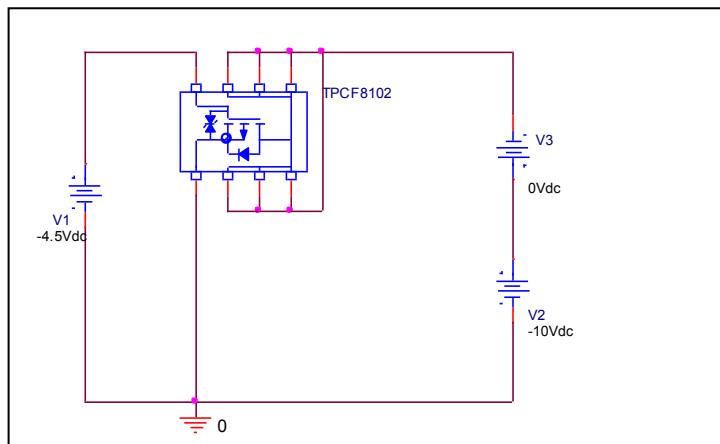
I_D (A)	V_{GS} (V)		Error (%)
	Measurement	Simulation	
-0.200	-1.225	-1.242	1.412
-0.500	-1.290	-1.302	0.922
-1.000	-1.370	-1.371	0.044
-2.000	-1.460	-1.471	0.740
-5.000	-1.655	-1.680	1.498

Rds(on) Characteristic

Circuit Simulation result



Evaluation circuit

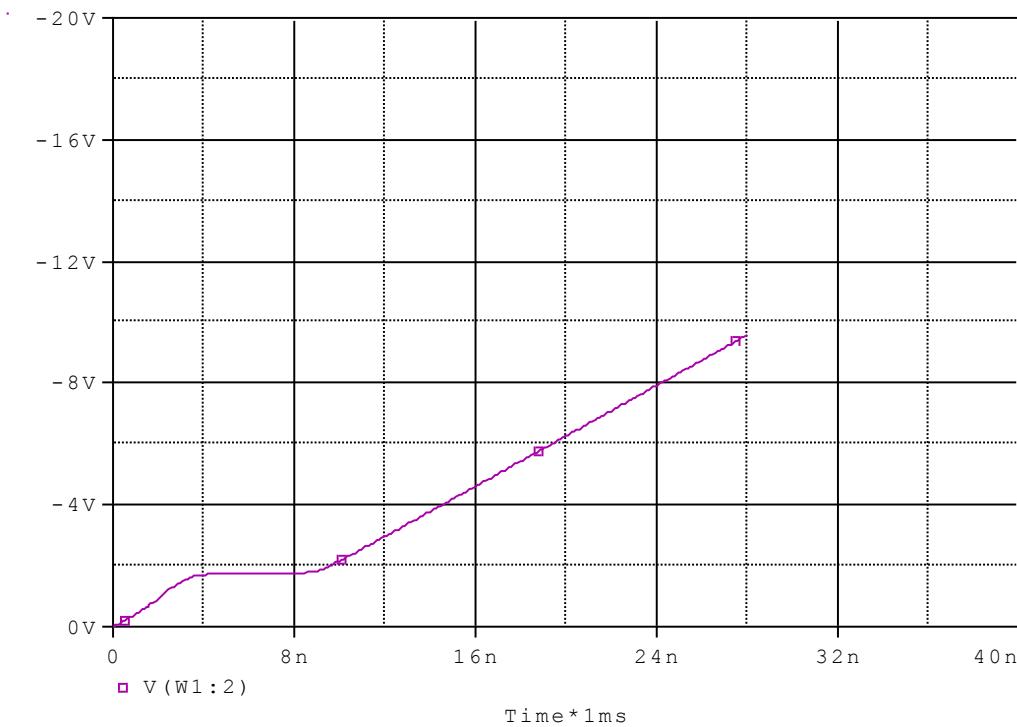


Simulation Result

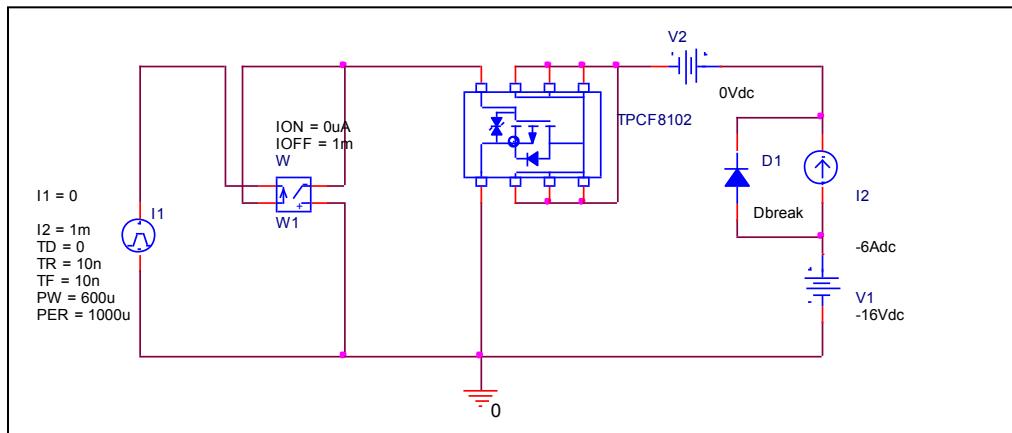
I _D =-3.0A, V _{GS} =-4.5V	Measurement		Simulation		Error (%)
R _{DS} (on)	24.000	mΩ	24.000	mΩ	0.000

Gate Charge Characteristic

Circuit Simulation result



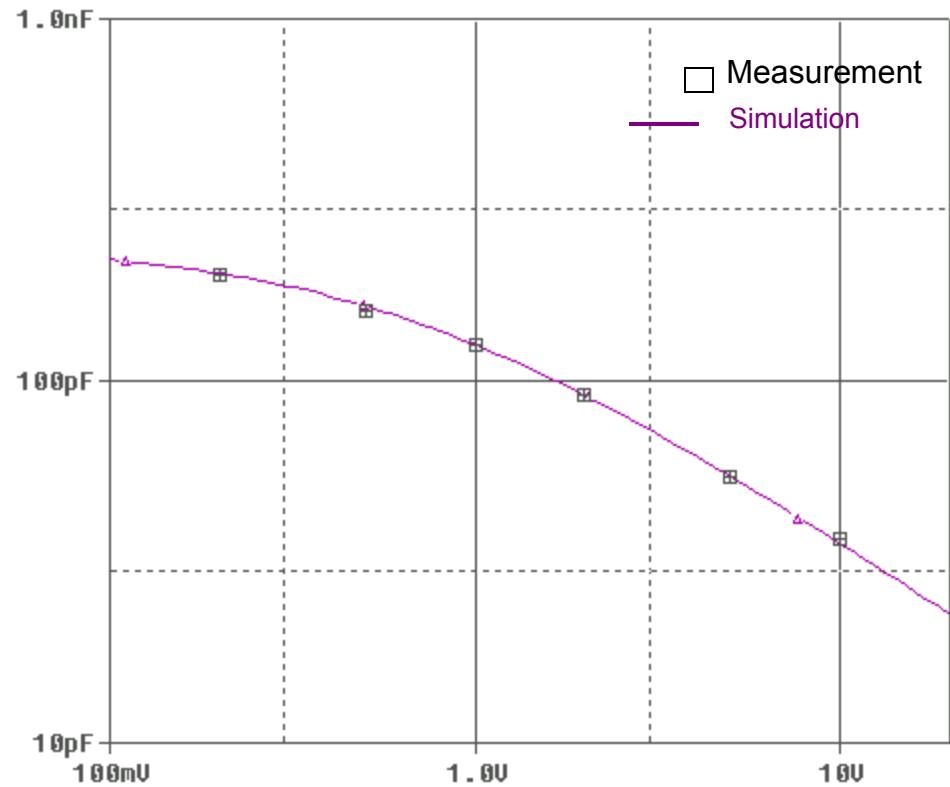
Evaluation circuit



Simulation Result

$V_{DD} = -16\text{V}, I_D = -6.0\text{A}$ $, V_{GS} = -5\text{V}$	Measurement		Simulation		Error (%)
Q_{gs}	4.000	nC	4.000	nC	0.000
Q_{gd}	5.000	nC	5.000	nC	0.000
Q_g	19.000	nC	16.956	nC	-10.758

Capacitance Characteristic

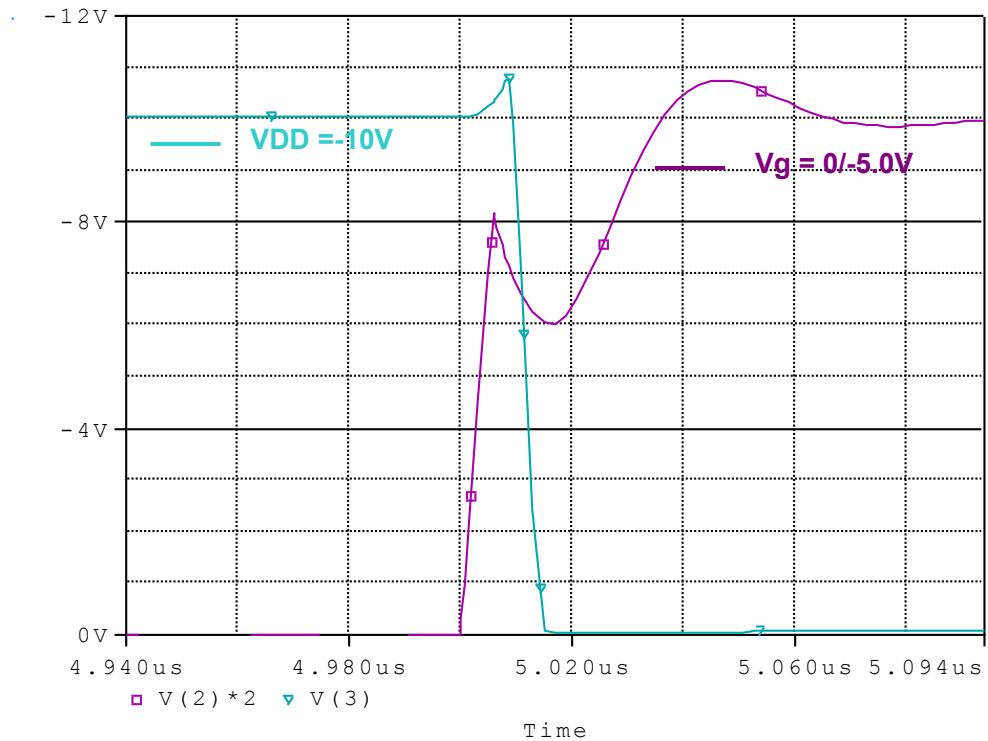


Simulation Result

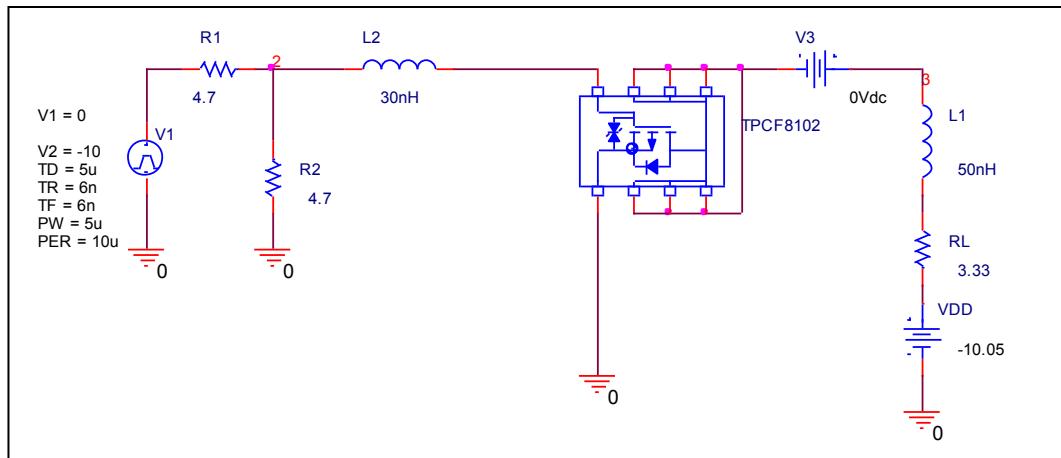
$V_{DS}(V)$	$C_{gd}(pF)$		Error(%)
	Measurement	Simulation	
0.200	200.000	198.000	-1.000
0.500	160.700	159.000	-1.058
1.000	127.000	125.000	-1.575
2.000	93.000	91.000	-2.151
5.000	55.000	54.450	-1.000
10.000	37.000	36.000	-2.703
20.000	23.000	22.700	-1.304

Switching Time Characteristic

Circuit Simulation result



Evaluation circuit

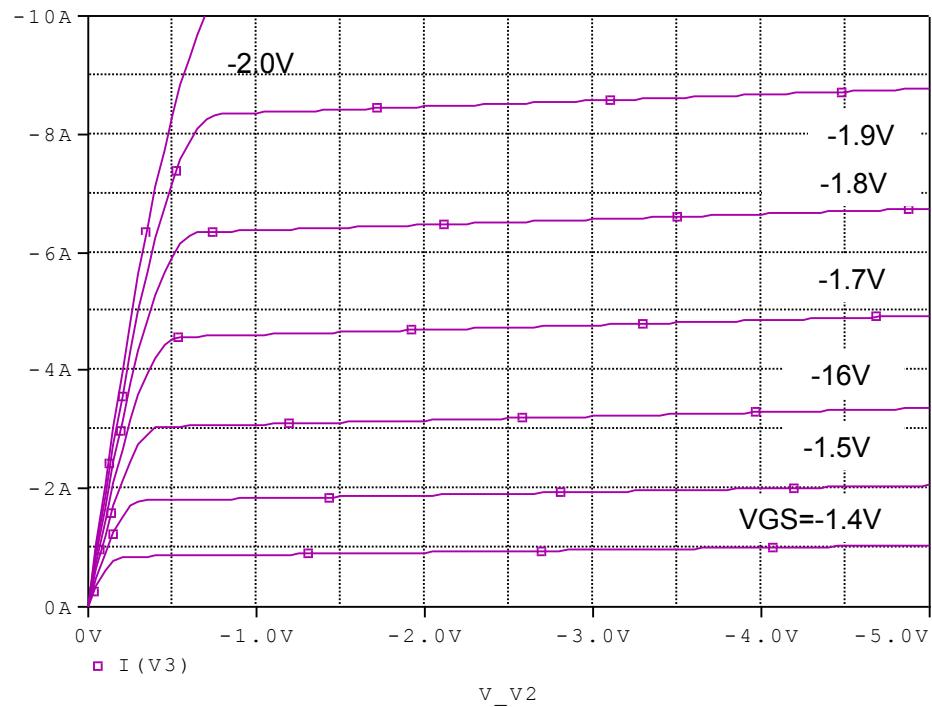


Simulation Result

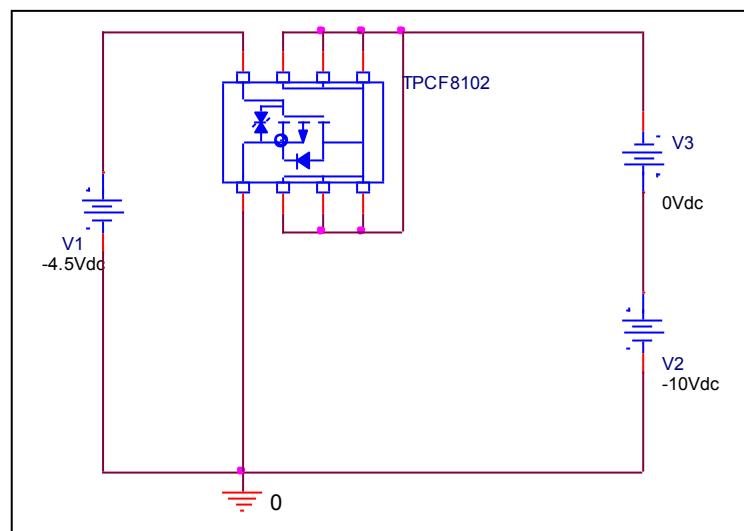
$I_D = -3.0A, V_{DD} = -10V$ $V_{GS} = 0/-5V$	Measurement	Simulation	Error(%)
ton	13.000 ns	13.576 ns	4.431

Output Characteristic

Circuit Simulation result

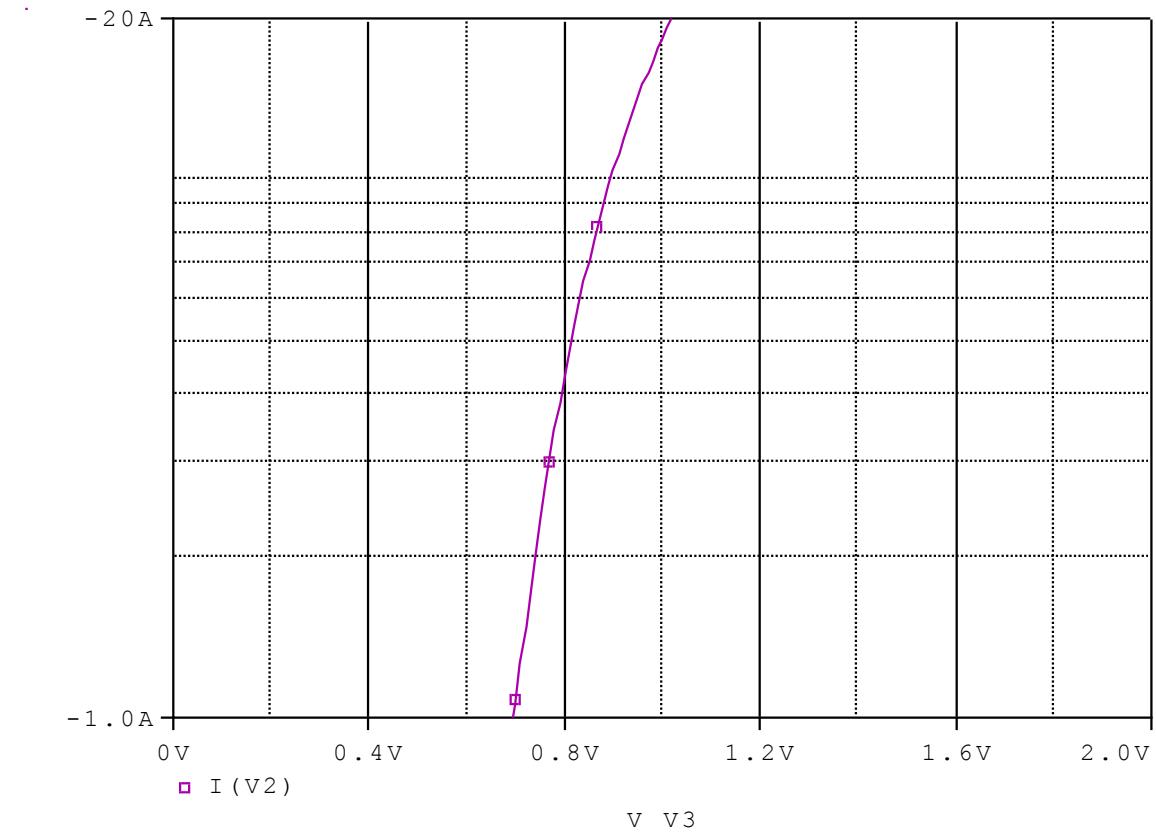


Evaluation circuit

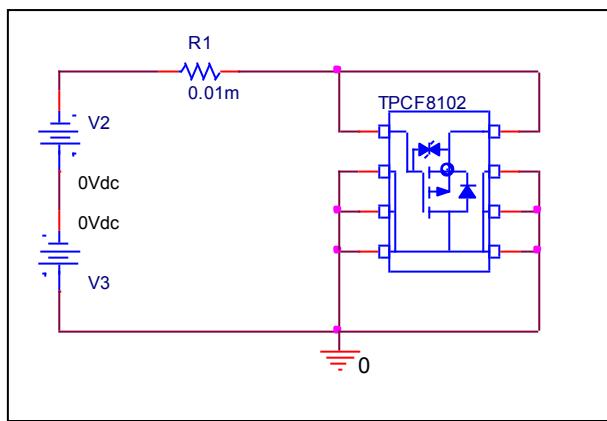


BODY DIODE SPICE MODEL Forward Current Characteristic

Circuit Simulation Result

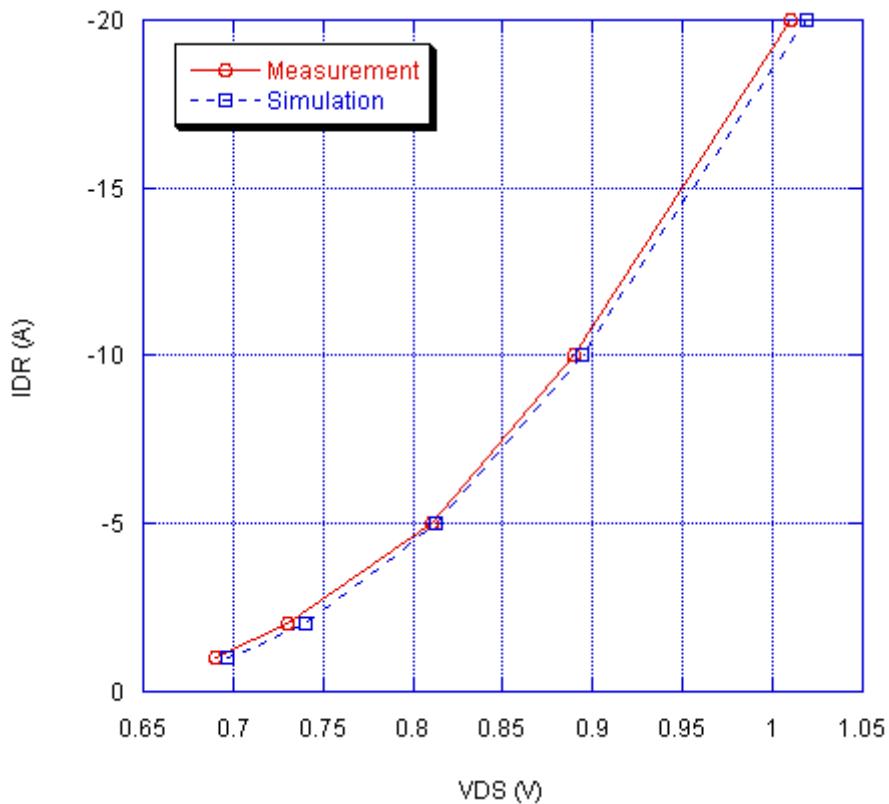


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

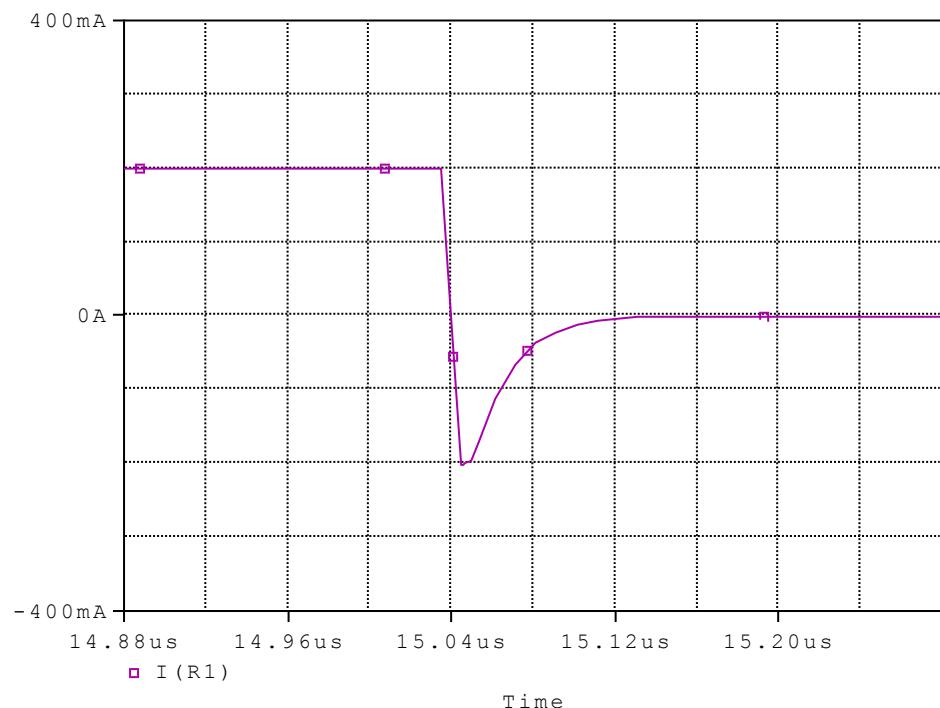


Simulation Result

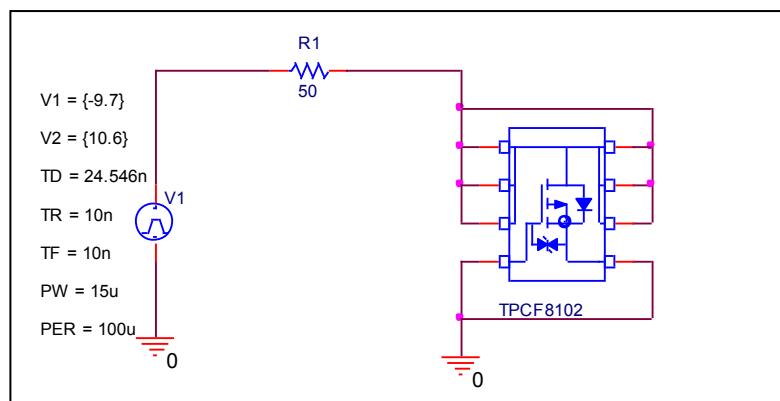
IDR (A)	VDS (V) Measurement	VDS (V) Simulation	%Error
-1.000	0.690	0.697	1.014
-2.000	0.730	0.740	1.370
-5.000	0.810	0.813	0.370
-10.000	0.890	0.894	0.449
-20.000	1.010	1.019	0.891
-1.000	0.690	0.697	1.014

Reverse Recovery Characteristic

Circuit Simulation Result



Evaluation Circuit

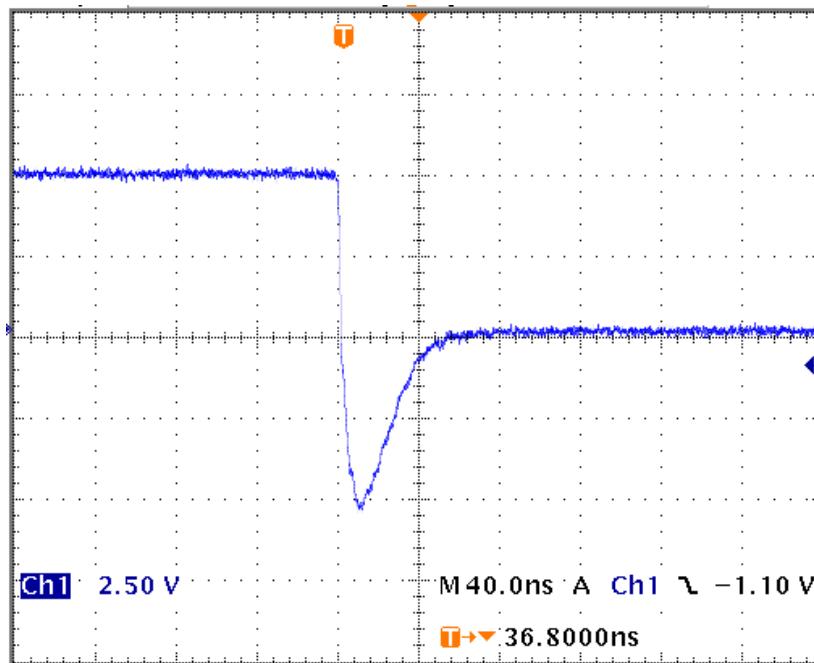


Compare Measurement vs. Simulation

	Measurement		Simulation		Error (%)
trj	8.800	ns	8.808	ns	0.091
trb	31.200	ns	45.098	ns	44.545
trr	40.000	ns	53.906	ns	34.765

Reverse Recovery Characteristic

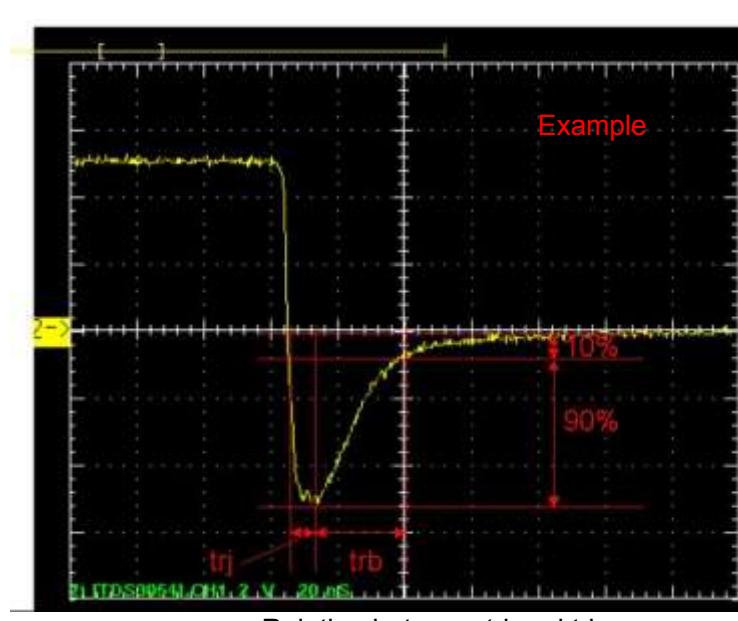
Reference



$$Trj=8.8(\text{ns})$$

$$Trb=31.2(\text{ns})$$

Conditions: Ifwd=Irev=0.2(A), RI=50

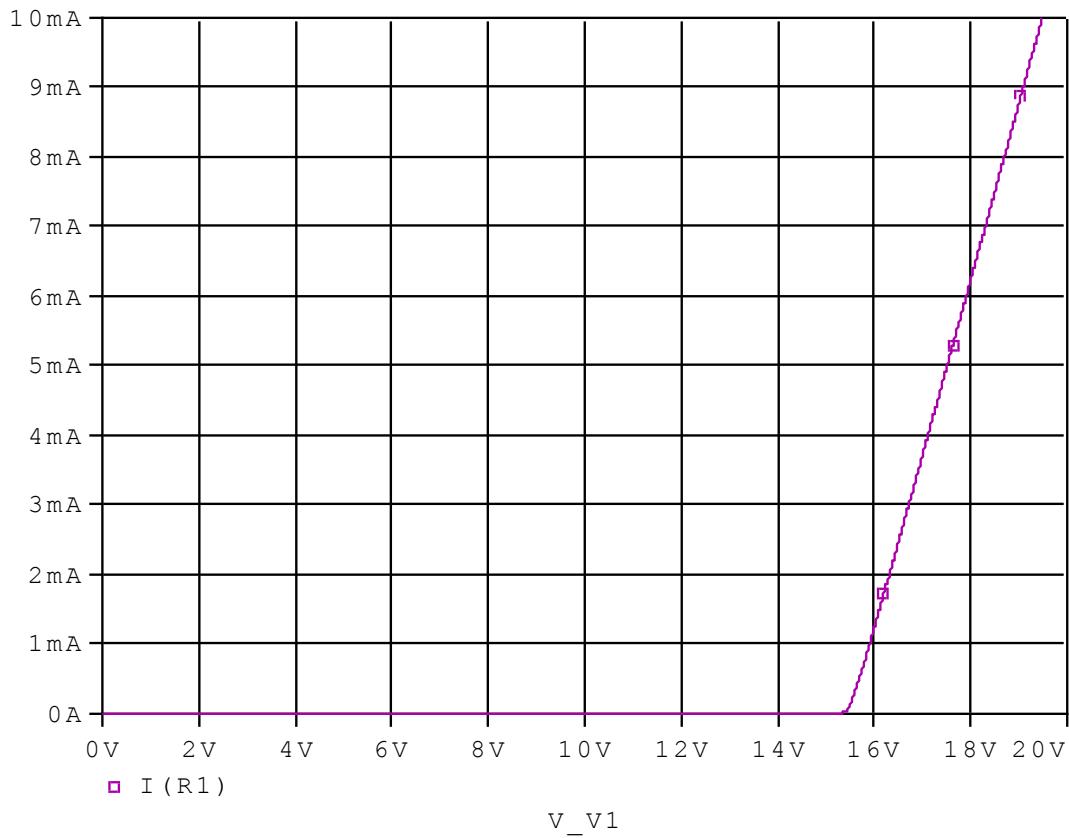


Relation between trj and trb

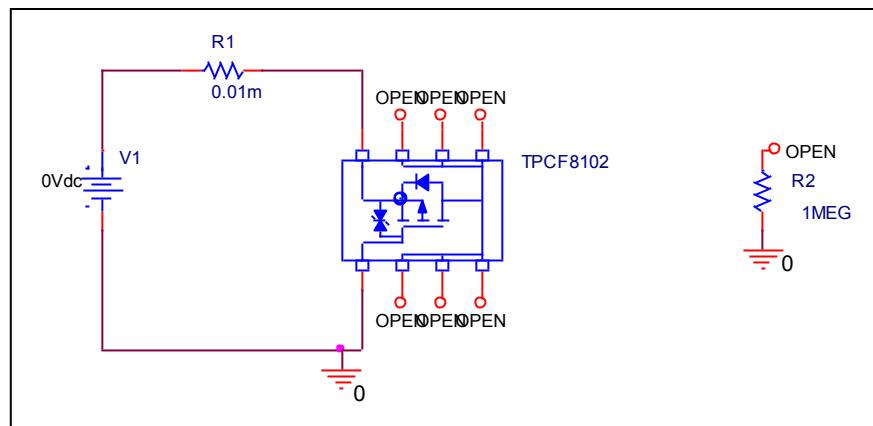
ESD PROTECTION DIODE SPICE MODEL

Zener Voltage Characteristic

Circuit Simulation Result



Evaluation Circuit



Zener Voltage Characteristic

Reference

